

NSS20501UW3T2G

NSS20501UW3T2G Information

	 NSS20501UW3T2G ON Semiconductor Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single TRANS NPN 20V 5A 3-WDFN 3-WDFN Exposed Pad For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



NSS20501UW3T2G Specifications

Manufacturer Part Number	NSS20501UW3T2G		
Manufacturer	ON Semiconductor		
Category	Discrete Semiconductor Products		
	Transistors - Bipolar (BJT) - Single		
Package	3-WDFN Exposed Pad		
Series	-		
Transistor Type	NPN		
Current - Collector (Ic) (Max)	5A		
Voltage - Collector Emitter Breakdown (Max)	20V		
Vce Saturation (Max) @ Ib, Ic	125mV @ 400mA, 4A		
Current - Collector Cutoff (Max)	100nA (ICBO)		
DC Current Gain (hFE) (Min) @ Ic, Vce	200 @ 2A, 2V		
Power - Max	875mW		
Frequency - Transition	150MHz		
Operating Temperature	-55°C ~ 150°C (TJ)		
Mounting Type	Surface Mount		
Package / Case	3-WDFN Exposed Pad		
Supplier Device Package	3-WDFN (2x2)		
	Report errors?		

NSS20501UW3T2G Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

NSS20501UW3T2G Payment Methods





If you have any question about NSS20501UW3T2G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com